

ASSIGNMENT-1

Answer-1:-

i) Maximum peak to peak voltage = 60V

$$\therefore V_m = \frac{60}{2} = 30V$$

$$\therefore \text{Peak current } (I_m) = \frac{V_m}{r_d + R_L} \quad \left\{ \begin{array}{l} \text{where } R_L = 500\Omega \\ \text{and } r_d = 50\Omega \end{array} \right.$$

$$\therefore I_m = \frac{30}{50 + 500} = \underline{\underline{0.054A}}$$

$$\text{Average Current } (I_{avg.}) = \frac{2 I_m}{\pi} = \frac{2 \times 0.054}{3.14} = \underline{\underline{0.034A}}$$

$$\text{RMS value of current } (I_{rms}) = \frac{I_m}{\sqrt{2}} = \frac{0.054}{\sqrt{2}} = \underline{\underline{0.038A}}$$

$$ii) \text{ Form Factor} = \frac{I_{rms}}{I_{avg.}} = \frac{\pi}{2\sqrt{2}} = 1.11$$

$$\therefore \text{Ripple Factor} = \sqrt{(1.11)^2 - 1} = \underline{\underline{0.481}}$$

$$iii) \text{ Efficiency} = \frac{1}{(1.11)^2 \left(1 + \frac{50}{500}\right)} = \frac{1}{(1.11)^2 (1.1)} = \underline{\underline{73.78\%}}$$

Answer 2:-

$$I_s = 5 \times 10^{-6} A, I_0 = 50 \times 10^{-3} A, L = 1 \text{ for Ge.}$$

$$T = 300K,$$

$$\text{We know } V_T = \frac{kT}{q} \quad \left\{ \begin{array}{l} \text{where } k = 1.38 \times 10^{-23} \text{ J/K and } q = 1.60 \times 10^{-19} \text{ C} \end{array} \right.$$

$$\therefore V_T = \frac{1.38 \times 10^{-23} \times 300}{1.6 \times 10^{-19}} = 0.0258$$

We know, $I_0 = I_s \left[e^{\frac{V_0}{V_T}} - 1 \right]$

$\therefore 50 \times 10^{-8} = 5 \times 10^{-6} \left[e^{\frac{V_0}{0.0258}} - 1 \right]$

$\Rightarrow e^{\frac{V_0}{0.0258}} = 10001$

$\Rightarrow \frac{V_0}{0.0258} = \ln(10001)$

$\Rightarrow V_0 = 9.21 \times 0.0258 = \underline{0.2376 \text{ V}}$

Answer - 3:-

a) Avalanche Breakdown

Zener Breakdown

i) The breakdown value is greater than 8V.

The breakdown value is between 5V and 8V.

ii) Increase in temperature increases the breakdown voltage.

Increase in temperature decreases the breakdown voltage.

iii) Occurs in diodes that are lightly doped.

Occurs in diodes that are heavily doped.

b) Drift Current

Diffusion Current

i) Electric field / biasing is required.

Electric field / biasing is not required.

ii) Caused due to the flow of minority charge carriers.

Caused due to the flow of minority charge carriers.

iii) Ohm's Law can be applied

Ohm's Law cannot be applied.

Answer - 4:-

$$V_{DD} = 5V, R = 1 \times 10^3 \Omega, V_t = 0.65V, r_d = 20 \Omega$$

Applying KVL in the circuit :-

$$-V_{DD} + V_t + I_D (R + r_d) = 0$$

$$\Rightarrow I_D = \frac{V_{DD} - V_t}{R + r_d}$$

$$\Rightarrow I_D = \frac{5 - 0.65}{1 \times 10^3 + 20} = 4.264 \times 10^{-3} A$$
$$= \underline{\underline{4.264 \text{ mA}}}$$